NSN 5961-00-768-2963

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-768-2963 **Inclosure Material:** Metal **Overall Length:** 1.060 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.060 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 10.0 forward voltage, peak and 5.0 reverse gate to source voltage **Current Rating Per Characteristic:** 130.00 milliamperes zero-gate-voltage source current horsepower metric **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 uninsulated wire lead w/terminal lug and 1 insulated wire lead w/terminal lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0